FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE(mini type)

DESCRIPTION

2SA1235 is a mini package resin sealed silicon PNP epitaxial transistor,

It is designed for low frequency voltage application.

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FEATURE

Small collector to emitter saturation voltage.

VCE(sat)=-0.3V max(@Ic=-100mA,IB=-10mA)

- ●Excellent linearity of DC forward gain.
- Super mini package for easy mounting

APPLICATION

For Hybrid IC,small type machine low frequency voltage Amplify application.

MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector to Base voltage -50		٧
V_{CEO}	Collector to Emitter voltage	-50	٧
V_{EBO}	Emitter to Base voltage	-6	٧
I o	Collector current	-200	mA
P _c	Collector dissipation	200	mW
T _j	Junction temperature +150		°C
T_{stg}	Storage temperature	-55 ~ +150	°C

JEITA: SC-59 JEDEC: Similar to TO-236 TERMINAL CONNECTER ①: BASE ②: EMITTER ③: COLLECTOR

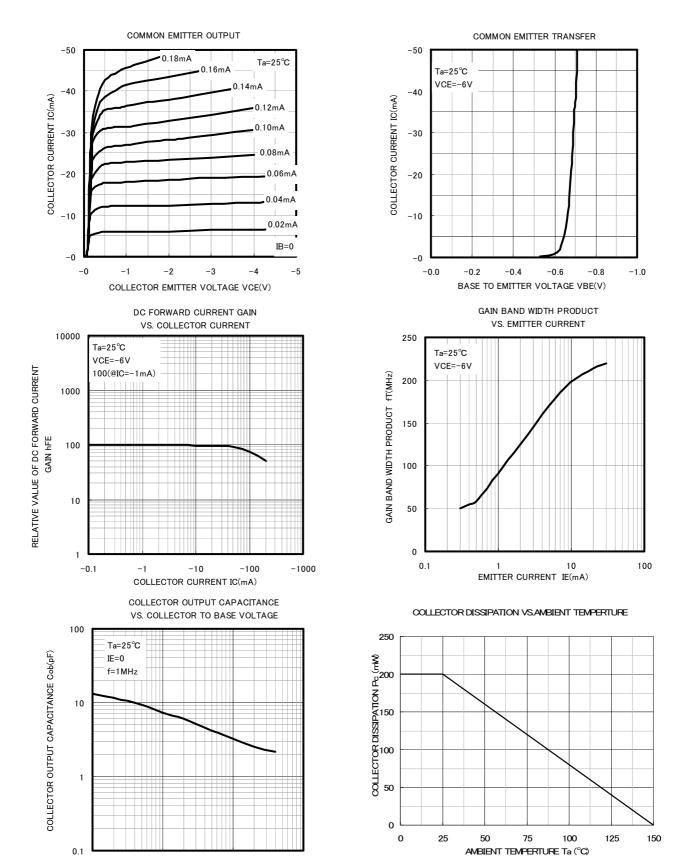
ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Test conditions		Limits		
Parameter	Symbol Test conditions		Min	Тур	Max	Unit
C to E break down voltage	V(BR)ceo	I $_{\text{C}}$ =-100 μ A ,R $_{\text{BE}}$ = ∞	-50	-	-	V
Collector cut off current	ICBO	V_{CB} =-50V, I $_{E}$ =0mA	-	-	-0.1	μΑ
Emitter cut off current	IEBO	V_{EB} =-6V, I $_{C}$ =0mA	-	-	-0.1	μΑ
DC forward current gain	hFE	V _{CE} =-6V, I _C =-1mA	150	-	800	
DC forward current gain	hFE	V_{CE} =-6V, I_{C} =-0.1mA	90	-	-	
C to E Saturation Vlotage	VCE(sat)	I_{C} =-100mA , I_{B} =-10mA	-	-	-0.3	V
Gain bandwidth product	fT	V _{CE} =-6V, I _E =10mA	-	200	-	MHz
Collector output capacitance	Cob	V_{CB} =-6V, I_{E} =0,f=1MHz	-	4	-	pF
Noise figure	NF	V _{CE} =-6V, I _E =0.3mA,f=100Hz,RG=10k Ω	_	-	20	dB

※) It shows hFE classification in below table.

Item	E	F	G
hFE Item	150~300	250~500	400~800

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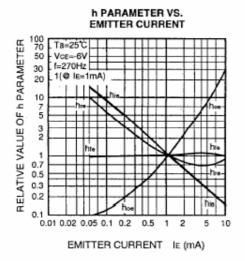
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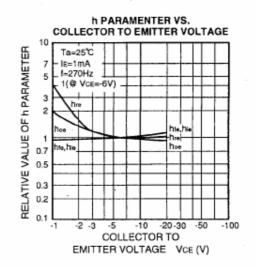
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COLLECTOR TO BASE VOLTAGE VCB(V)

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COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hie	Closed loop small signal input impedance	Ta=25°C	7.0	kΩ
hre	Open loop small signal reverse voltage amplification factor	Vce=-6V	0.1	X10-3
hte	Closed loop small signal forward current amplification factor	IE=1mA	250	
hos	Open loop small signal output admittance	f=270Hz	18	μS



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